

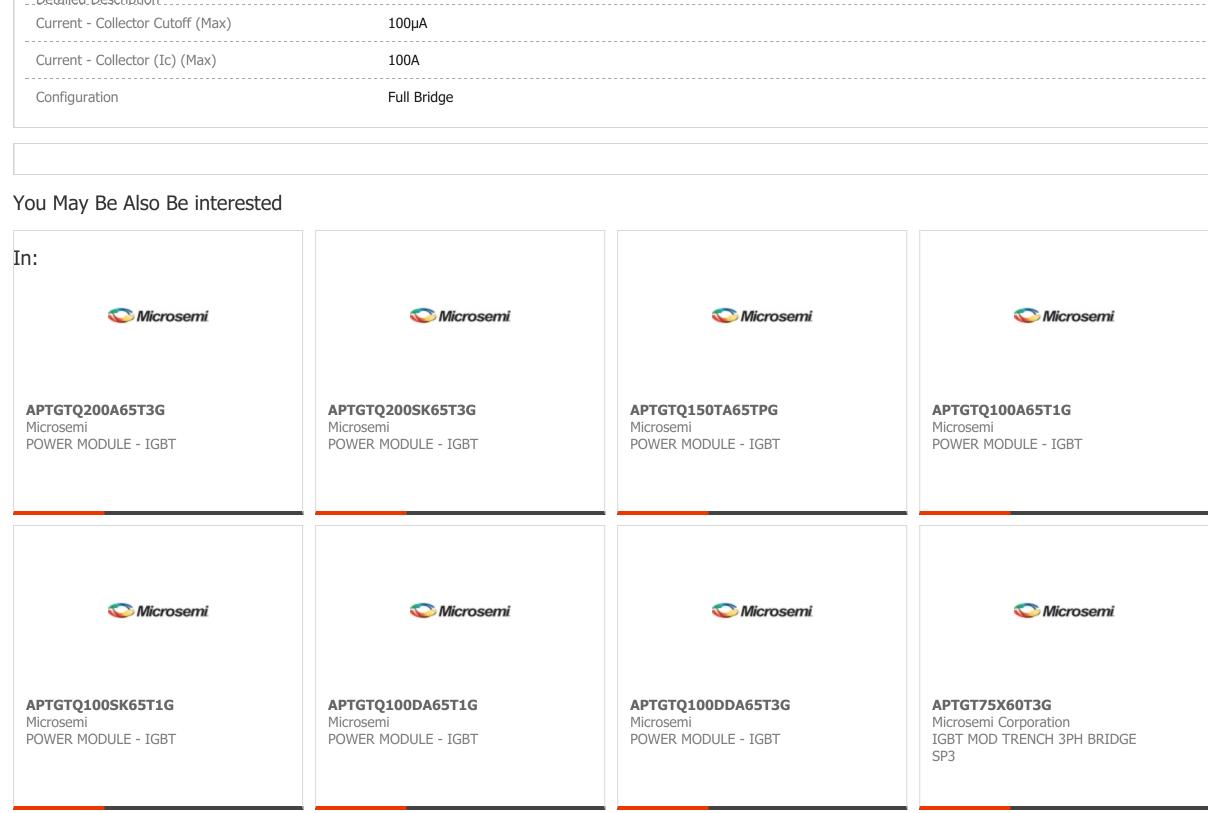


Image may be representation. See specs for product details. **Shipment Way:**

APTGTQ100H65T3G **Manufacturer Part Number:** APTGTQ100H65T3G **Manufacturer/Brand:** Microsemi **Part of Description:** POWER MODULE - IGBT **Datasheets:** 🔂 APTGTQ100H65T3G.pdf RoHS Lead free / RoHS **RoHs Status:** Compliant New original, 2692 pcs Stock Available. **Stock Condition: Ship From:** Hong Kong

DHL/Fedex/TNT/UPS/EMS

Specifications	
Part Number	APTGTQ100H65T3G
Manufacturer	Microsemi
Description	POWER MODULE - IGBT
Category	Discrete Semiconductor Products > Transistors - IGBTs -
Part Status	2692 pcs Stock
Voltage - Collector Emitter Breakdown (Max)	650V
Vce(on) (Max) @ Vge, Ic	2.2V @ 15V, 100A
Supplier Device Package	SP3F
Series	-
Power - Max	250W
Package / Case	Module
Operating Temperature	-40°C ~ 175°C (TJ)
NTC Thermistor	Yes
Mounting Type	Chassis Mount
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Input Capacitance (Cies) @ Vce	6nF @ 25V
Input	Standard
IGBT Type	-
Detailed Description	IGBT Module Full Bridge 650V 100A 250W Chassis
Current - Collector Cutoff (Max)	100µA
Current - Collector (Ic) (Max)	100A
Configuration	Full Bridge



APTGTQ100H65T3G Related keyword

APTGTQ100H65T3G Microsemi
APTGTQ100H65T3G Electronic
APTGTQ100H65T3G Price
APTGTQ100H65T3G New

APTGTQ100H65T3G Data Sheet
APTGTQ100H65T3G Components
APTGTQ100H65T3G Manufacturer
APTGTQ100H65T3G Original

APTGTQ100H65T3G Datasheets
APTGTQ100H65T3G Distributor
APTGTQ100H65T3G Picture
APTGTQ100H65T3G Warranted

APTGTQ100H65T3G PDF

APTGTQ100H65T3G Image

APTGTQ100H65T3G Stock

APTGTQ100H65T3G RFQ

Microsemi APTGTQ100H65T3G

APTGTQ100H65T3G Part

APTGTQ100H65T3G Inventory

APTGTQ100H65T3G Order Online

More